## ECE 320 - Quiz #2 - Name

Semiconductors, pn Junction, ideal diodes - Spring 2022

1a) What are holes and electrons?

1b) The voltage drop across a silicon diode is about 0.7V.

- Does this voltage go up or down as temperature goes up?
- Why does this happen?

- 2) An 0603 resistor has the following dimensions
  - L = 0.06cm
  - W = 0.03cm
  - H = 0.02cm

Determine the doping required to make a resistance of R ohms where

- $R = 1200 + 100^{*}$ (your birth month) + (your birth date).
- For example, May 14th would give R = 1714 Ohms

R	Required Doping of Boron
1200 + 100*(your birth month) + (your birth date)	atoms / cc

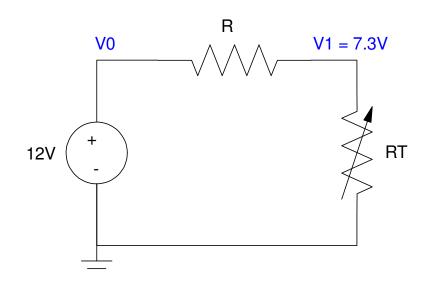
3) Thermistors: Assume the VI characteristics of a thermistor are

$$R_T = 2000 \exp\left(\frac{4350}{T + 273} - \frac{4350}{298}\right) \Omega$$

where T is the temperature in degrees C. Determine RT and the temperature if V1 = 7.3V

• Let R be 1200 + (your birth month) \* 100 + your birthday. (March 14th would give R = 1714 Ohms)

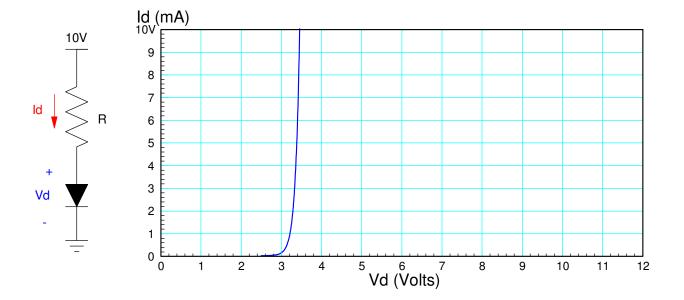
<b>R</b> 1200 + 100*Month + Day	RT (Ohms) Thermistor	Temperature (C)	



4) Load Lines: The VI characteristic for a diode is show on the graph below. Draw the load line for the following circuit and from the graph, determine Vd and Id

Load Line x-intercept	Load Lie y-intercept	Vd	ld

• Let R be 1200 + 100\*(Birth Month) + (Birthday)



5) Diodes (nonlinear equations): Assume

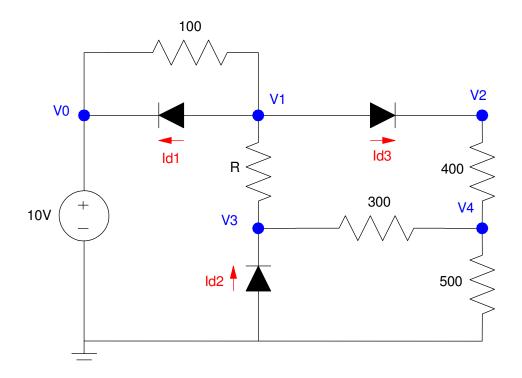
• The VI characteristics of a diode are

$$I_d = 10^{-11} \cdot \left( \exp\left(\frac{V_d}{0.038}\right) - 1 \right)$$

• R = 1200 + 100 \* (your birth month) + (your birth date).

Write 7 equations so solve for 7 unknowns: V1, V2, V3, V4, Id1, Id2, Id3

• note: don't solve.



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